

L Number	Hits	Search Text	DB	Time stamp
1	0	resist\$3 near5 polysilicon and series and input near3 outpout near5 terminal\$ and switch\$2	USPAT; EPO; JPO; DERWENT	2004/09/22 09:36
2	6223	resist\$3 near5 polysilicon	USPAT; EPO; JPO; DERWENT	2004/09/22 09:37
3	1	series and input near3 outpout near5 terminal\$ and switch\$2	USPAT; EPO; JPO; DERWENT	2004/09/22 09:38
4	2	input near3 outpout near5 terminal\$ and switch\$2	USPAT; EPO; JPO; DERWENT	2004/09/22 09:38
5	813	(resist\$3 near5 polysilicon) and terminal\$ and switch\$2	USPAT; EPO; JPO; DERWENT	2004/09/22 09:39
6	0	((resist\$3 near5 polysilicon) and terminal\$ and switch\$2) and transistor and p adj cchannel and n adj channel	USPAT; EPO; JPO; DERWENT	2004/09/22 09:40
7	367	((resist\$3 near5 polysilicon) and terminal\$ and switch\$2) and transistor and p adj channel and n adj channel	USPAT; EPO; JPO; DERWENT	2004/09/22 09:40
8	264	((resist\$3 near5 polysilicon) and terminal\$ and switch\$2) and transistor and p adj channel and n adj channel) and MOS	USPAT; EPO; JPO; DERWENT	2004/09/22 09:55
9	0	((((resist\$3 near5 polysilicon) and terminal\$ and switch\$2) and transistor and p adj channel and n adj channel) and MOS) and program\$5 adj2 terminal	USPAT; EPO; JPO; DERWENT	2004/09/22 09:56
10	75	((((resist\$3 near5 polysilicon) and terminal\$ and switch\$2) and transistor and p adj channel and n adj channel) and MOS) and first adj2 terminal and second adj2 terminal	USPAT; EPO; JPO; DERWENT	2004/09/22 09:56